



SUBJECT AREAS:
ELECTRONIC PROPERTIES
AND MATERIALS
CONDENSED-MATTER PHYSICS

CORRIGENDUM: Multiple π -bands and Bernal stacking of multilayer graphene on C-face SiC, revealed by nano-Angle Resolved Photoemission

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The authors neglected to cite a related study that reports an ARPES experiment indicating the presence of multiple π bands in multilayer graphene on C-face SiC.¹ This is given below as Reference 1. In the present Article, nano-ARPES band mappings of individual graphene grains unambiguously show that multilayer C-face graphene exhibits multiple π -bands.

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Reference

1. D. A. Siegel, C. G. Hwang, A. V. Fedorov, and A. Lanzara Quasifreestanding multilayer graphene films on the carbon face of SiC. *Phys. Rev. B* **81**, 241417 (R) (2010) DOI: 10.1103/PhysRevB.81.241417.